Solid State Devices - Video course

TOPIC	No. of lectures		
Introduction	1		
Evolution and uniqueness of Semiconductor Technology	1		
Equilibrium carrier concentration Thermal Equilibrium and wave particle duality Intrinsic semiconductor ø Bond and band models Extrinsic semiconductor ø Bond and band models	5		
Carrier transport Random motion Drift and diffusion	2		
Excess carriers Injection level Lifetime Direct and indirect semiconductors	2		
Procedure for analyzing semiconductor devices Basic equations and approximations	1		
P-N Junction Device structure and fabrication Equilibrium picture DC forward and reverse characteristics Small-signal equivalent circuit Switching characteristics Solar cell	6		
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Bipolar Junction Transistor History Device structures and fabrication Transistor action and amplification Common emitter DC characteristics Small-signal Equivalent circuit vEbers-Moll model SPICE model	6		
MOS Junction C-V characteristics, threshold voltage, body effect	3		
Metal Oxide Field Effect Transistor History Device structures and fabrication Common source DC characteristics Small-signal equivalent circuit SPICE level-1 model	8		



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Electronics & Communication Engineering

Coordinators:

Prof. S. KarmalkarDepartment of Electrical EngineeringIIT Madras

Differences between a MOSFET and a BJT		
Junction FET and MESFET	2	
Recent Developments Heterojunction FET Hetrojunction bipolar transistor	2	
Summary	1	
Total number of lectures	40	

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